

B.TECH
(SEM IV) THEORY EXAMINATION 2022-23
ELECTRONICS ENGINEERING

*Time: 3 Hours**Total Marks: 100***Note:** Attempt all Sections. If require any missing data; then choose suitably.**SECTION A**

- 1. Attempt all questions in brief. 2 x 10 = 20**
- Breakdown voltage of a zener diode is 10V. It can dissipate a maximum power of 350 mW. Determine the maximum current the diode can handle?
 - What you mean by Doping.
 - Explain the principle of operation of LED.
 - What is meant by voltage multiplier?
 - Define Threshold Voltage for an E-MOSFET.
 - Define transconductance of JFET.
 - Explain the concept of Virtual ground in an OPAMP.
 - Draw the structure of Integrator using OP-AMP.
 - What are the applications of CRO?
 - For what purpose, digital multimeter are used?

SECTION B

- 2. Attempt any three of the following: 10 x 3 = 30**
- Draw & explain the V-I characteristic of a P-N junction diode. Also describe the effect of Temperature on the V-I characteristic of a P-N junction diode.
 - Explain principle of operation and construction of Varacter diode. Draw its V-I characteristic.
 - With help of a well labeled diagram, discuss input and output characteristics of a bipolar junction transistor in common base configuration. Also indicate all the regions of operation
 - Explain unity gain OPAMP. With suitable circuit diagram obtain the expression for integrator and differentiator OPAMP.
 - Draw and explain the block diagram of Ramp type digital voltmeter. Also draw related voltage to time conversion waveforms

SECTION C

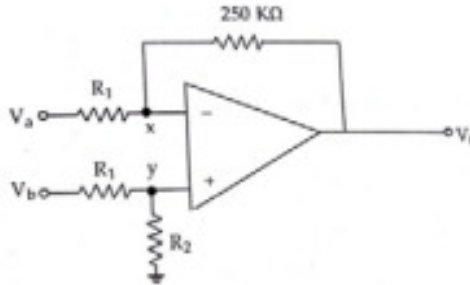
- 3. Attempt any one part of the following: 10 x 1 = 10**
- Explain how a barrier potential is developed at the P-N junction
 - Draw and explain the circuit diagram for negative and positive clamper circuits with input and output waveforms.
- 4. Attempt any one part of the following: 10 x 1 = 10**
- Explain principle of operation and construction of Tunnel diode. Draw its V-I characteristic.
 - Draw the circuit and discuss the working of full wave bridge rectifier with suitable input -output waveforms. What is PIV of bridge rectifier?

5. Attempt any *one* part of the following: 10 x 1 = 10

- (a) Draw the circuit of transistor in the CE configuration. Sketch the output characteristic. Indicate the Active, saturation region and cut-off region. Explain each region in detail.
- (b) Draw and explain the construction and working of p-channel depletion type MOSFET. Also draw the characteristics of p-channel depletion type MOSFET.

6. Attempt any *one* part of the following: 10 x 1 = 10

- (a) For the op-amp shown in figure , find the values of R_1 and R_2 for the output to be $V_0 = -5V_a + 3V_b$



- (b) Explain the non-inverting summing amplifier with circuit diagram.

7. Attempt any *one* part of the following: 10 x 1 = 10

- (a) Describe the operation of CRT with neat block diagram. How unknown frequency is measured using CRO?
- (b) Compare DSO with analog oscilloscope.